



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

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企业微信二维码



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Feature

- $BV_{CEO} > 40V$
- $I_C = 1A$ Continuous Collector Current
- $I_{CM} = 2A$ Peak Pulse Current
- $R_{CE(sat)} = 195m\Omega$ for a Low Equivalent On-Resistance
- 500mW Power Dissipation
- h_{FE} Characterised up to 2A for High Current Gain Hold Up

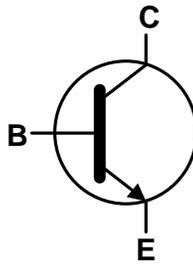
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per
MIL-STD-202, Method 208 
- Weight 0.008 grams (Approximate)

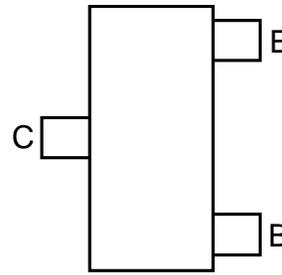
SOT23 (Type DN)



Top View



Device Symbol



Top View
Pin-Out

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	40	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	1	A
Peak Pulse Current	I _{CM}	2	A
Base Current	I _B	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

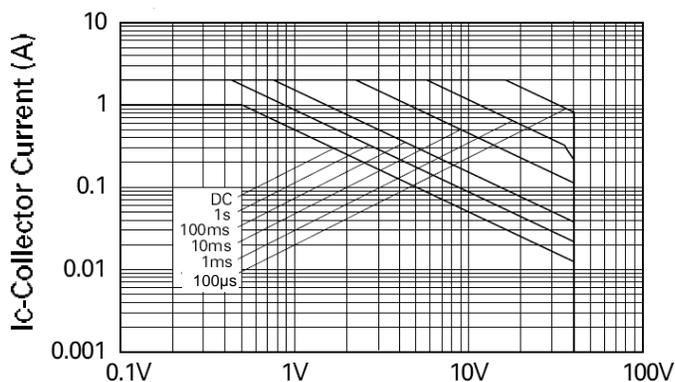
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	250	°C/W
Thermal Resistance, Junction to Lead (Note 7)	R _{θJL}	197	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

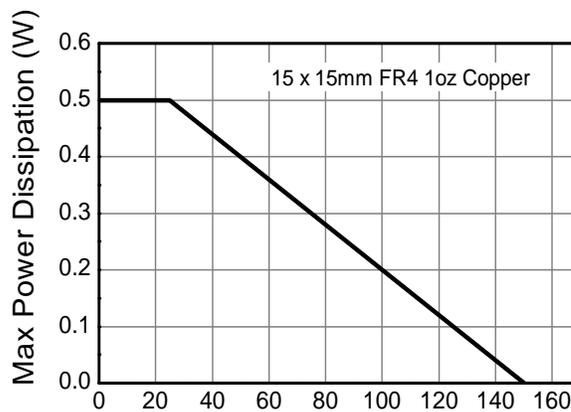
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

- Notes:
6. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

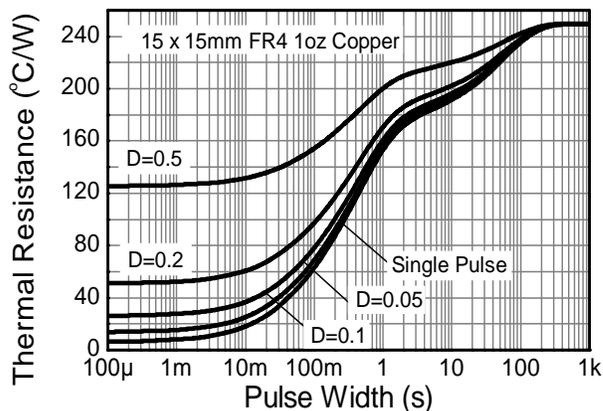
Thermal Characteristics and Derating Information



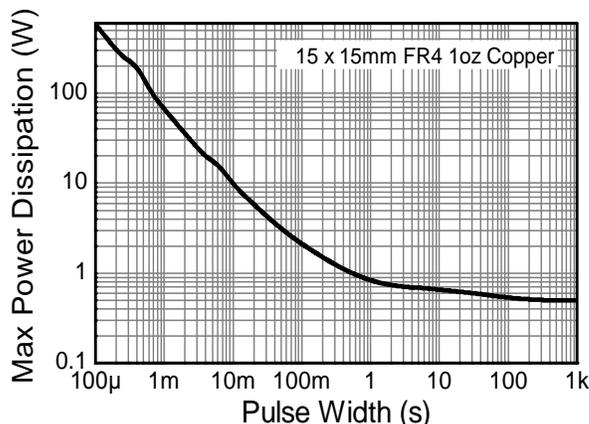
VCE - Collector Emitter Voltage (V)
Safe Operating Area



Temperature (°C)
Derating Curve



Transient Thermal Impedance



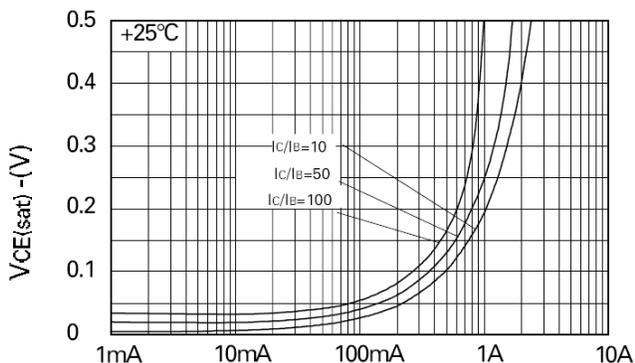
Pulse Power Dissipation

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

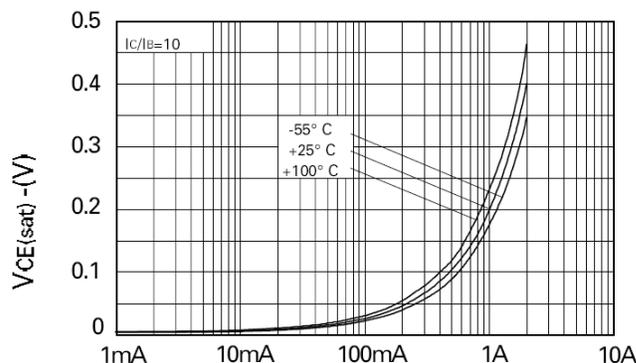
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	40	—	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	40	—	—	V	$I_C = 10\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	—	—	V	$I_E = 100\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	100	nA	$V_{CB} = 30\text{V}, V_{CES} = 30\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	100	nA	$V_{EB} = 5\text{V}$
Collector Emitter Cutoff Current	I_{CES}	—	—	100	nA	$V_{CE} = 30\text{V}, V_{CES} = 30\text{V}$
Static Forward Current Transfer Ratio (Note 9)	h_{FE}	300	—	—	—	$I_C = 1\text{mA}, V_{CE} = 5\text{V}$
		300	—	900		$I_C = 500\text{mA}, V_{CE} = 5\text{V}$
		200	—	—		$I_C = 1\text{A}, V_{CE} = 5\text{V}$
		35	—	—		$I_C = 2\text{A}, V_{CE} = 5\text{V}$
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	—	—	0.3	V	$I_C = 500\text{mA}, I_B = 50\text{mA}$
		—	—	0.5		$I_C = 1\text{A}, I_B = 100\text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	—	—	1.0	V	$I_C = 1\text{A}, V_{CE} = 5\text{V}$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	—	—	1.1	V	$I_C = 1\text{A}, I_B = 100\text{mA}$
Output Capacitance	C_{obo}	—	—	10	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$
Transition Frequency	f_T	150	—	—	MHz	$V_{CE} = 10\text{V}, I_C = 50\text{mA}, f = 100\text{MHz}$

Notes: 9. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

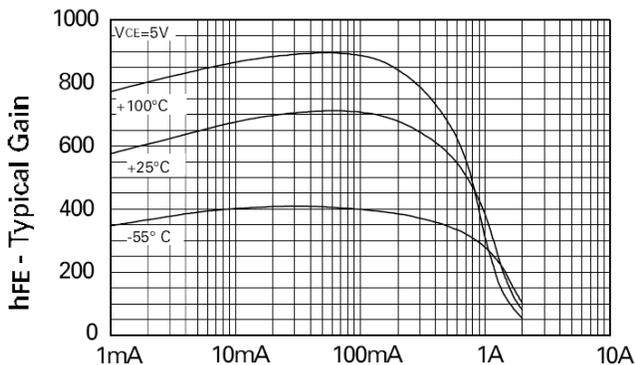
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



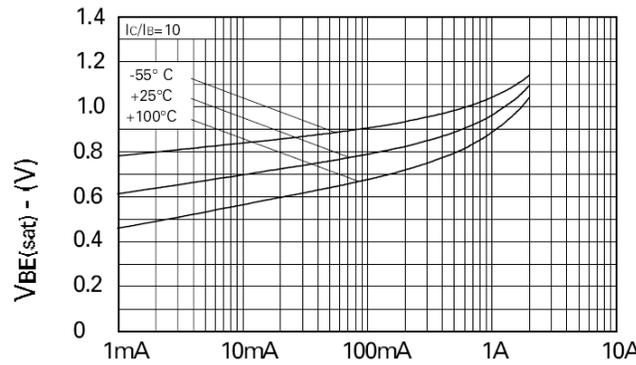
$V_{CE(sat)} \text{ v } I_C$



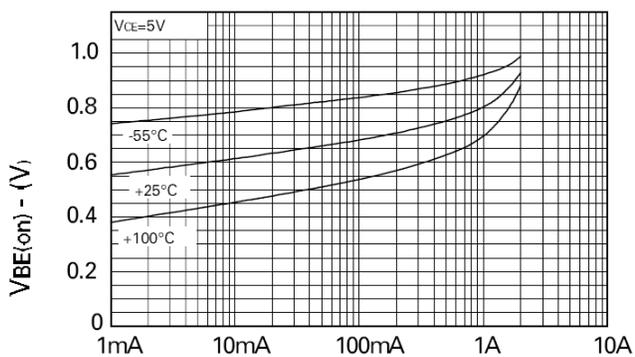
$V_{CE(sat)} \text{ v } I_C$



$h_{FE} \text{ v } I_C$



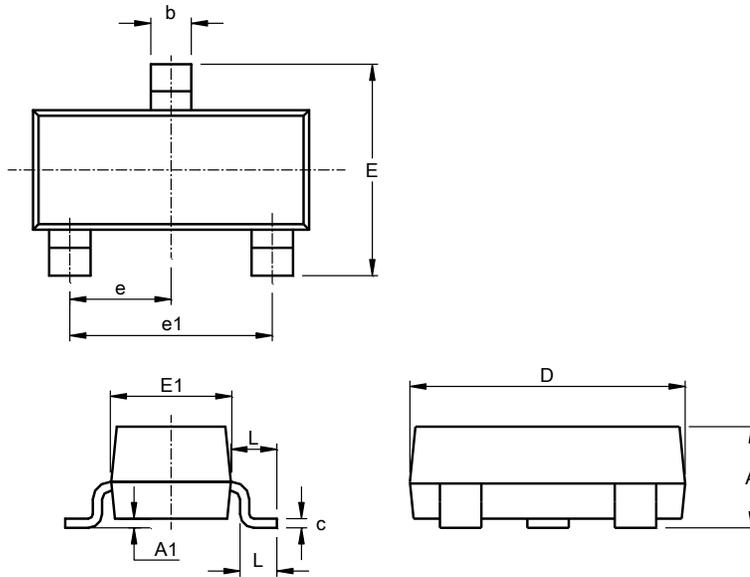
$V_{BE(sat)} \text{ v } I_C$



$V_{BE(on)} \text{ v } I_C$

Package Outline Dimensions

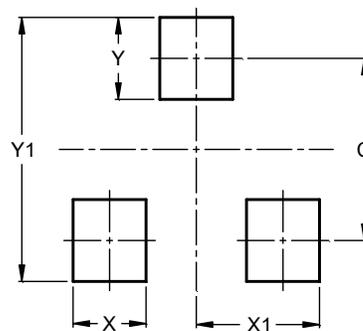
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Dim	Min	Max	Typ
A	0.89	1.12	1.00
A1	0.01	0.10	0.05
b	0.30	0.51	0.45
c	0.08	0.20	0.10
D	2.80	3.04	3.00
E	2.10	2.64	2.42
E1	1.20	1.40	1.37
e	0.95 REF		
e1	1.90 REF		
L	0.25	0.60	0.30
L1	0.45	0.62	0.54
All Dimensions in mm			

Suggested Pad Layout

SOT23 (Type DN)



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9